NSN 5961-01-009-0290

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View Online at https://aerobasegroup.com/nsn/5961-01-009-0290 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.250 inches and 0.340 inches Overall Diameter: 0.620 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 700.0 collector to base voltage/static/emitter open and 700.0 collector to emitter voltage, dc with specified circuit between base and emitter and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 13973-862117 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 case and 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig:

No

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